3.3V / 5V ECL D Flip-Flop with Reset and Differential Clock

The MC10/100EP51 is a differential clock D flip-flop with reset. The device is functionally equivalent to the EL51 and LVEL51 devices.

The reset input is an asynchronous, level triggered signal. Data enters the master portion of the flip-flop when the clock is LOW and is transferred to the slave, and thus the outputs, upon a positive transition of the clock. The differential clock inputs of the EP51 allow the device to be used as a negative edge triggered flip-flop.

The differential input employs clamp circuitry to maintain stability under open input conditions. When left open, the CLK input will be pulled down to V_{EE} and the \overline{CLK} input will be biased at $V_{CC}/2$.

The 100 Series contains temperature compensation.

- 350 ps Typical Propagation Delay
- Maximum Frequency > 3 GHz Typical
- PECL Mode Operating Range: V_{CC} = 3.0 V to 5.5 V with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -3.0 V to -5.5 V
- Open Input Default State
- Safety Clamp on Inputs



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MARKING DIAGRAMS*



SO-8 D SUFFIX CASE 751







TSSOP-8 DT SUFFIX CASE 948R



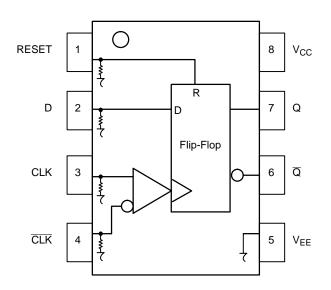


 $\begin{array}{ll} H = MC10 & L = Wafer Lot \\ K = MC100 & Y = Year \\ A = Assembly Location & W = Work Week \end{array}$

ORDERING INFORMATION

Device	Package	Shipping
MC10EP51D	SO-8	98 Units/Rail
MC10EP51DR2	SO-8	2500 Tape & Reel
MC100EP51D	SO-8	98 Units/Rail
MC100EP51DR2	SO-8	2500 Tape & Reel
MC10EP51DT	TSSOP-8	100 Units/Rail
MC10EP51DTR2	TSSOP-8	2500 Tape & Reel
MC100EP51DT	TSSOP-8	100 Units/Rail
MC100EP51DTR2	TSSOP-8	2500 Tape & Reel

^{*}For additional information, see Application Note AND8002/D



PIN DESCRIPTION

PIN	FUNCTION
CLK*, CLK*	ECL Clock Inputs
Reset*	ECL Asynchronous Reset
D*	ECL Data Input
Q, Q	ECL Data Outputs
V _{CC}	Positive Supply
V _{EE}	Negative Supply

^{*} Pins will default LOW when left open.

TRUTH TABLE

D	R	CLK	Q
L	L	Z	L
Н	L	Z	Н
Х	Н	Х	L

Z = LOW to HIGH Transition

Figure 1. 8-Lead Pinout (Top View) and Logic Diagram

ATTRIBUTES

Charact	eristics	Value
Internal Input Pulldown Resistor		75 kΩ
Internal Input Pullup Resistor		N/A
ESD Protection	Human Body Model Machine Model Charged Device Model	> 2 kV > 200 V > 2 kV
Moisture Sensitivity, Indefinite Ti	me Out of Drypack (Note 1.)	Level 1
Flammability Rating Oxygen Index		UL-94 code V-0 A 1/8" 28 to 34
Transistor Count		165 Devices
Meets or exceeds JEDEC Spec	EIA/JESD78 IC Latchup Test	

^{1.} For additional information, see Application Note AND8003/D.

MAXIMUM RATINGS (Note 2.)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		6	V
V _{EE}	NECL Mode Power Supply	V _{CC} = 0 V		-6	V
V _I	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$ \begin{array}{c} V_{I} \! \leq \! V_{CC} \\ V_{I} \! \geq \! V_{EE} \end{array} $	6 -6	V
l _{out}	Output Current	Continuous Surge		50 100	mA mA
TA	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W °C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction to Case)	std bd	8 SOIC	41 to 44	°C/W
$\theta_{\sf JA}$	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction to Case)	std bd	8 TSSOP	41 to 44	°C/W
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

^{2.} Maximum Ratings are those values beyond which device damage may occur.

10EP DC CHARACTERISTICS, PECL $V_{CC} = 3.3 \text{ V}$, $V_{EE} = 0 \text{ V}$ (Note 3.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	26	34	44	26	35	45	28	37	47	mA
V _{OH}	Output HIGH Voltage (Note 4.)	2165	2290	2415	2230	2355	2480	2290	2415	2540	mV
V _{OL}	Output LOW Voltage (Note 4.)	1365	1490	1615	1430	1555	1680	1490	1615	1740	mV
V _{IH}	Input HIGH Voltage (Single Ended)	2090		2415	2155		2480	2215		2540	mV
V_{IL}	Input LOW Voltage (Single Ended)	1365		1690	1430		1755	1490		1815	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 5.)	2.0		3.3	2.0		3.3	2.0		3.3	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfpm is maintained.

- 3. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.3 V to -2.2 V.
- 4. All loading with 50 ohms to V_{CC} -2.0 volts.
- 5. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

10EP DC CHARACTERISTICS, PECL $V_{CC} = 5.0 \text{ V}$, $V_{EE} = 0 \text{ V}$ (Note 6.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	26	34	44	26	35	45	28	37	47	mA
V _{OH}	Output HIGH Voltage (Note 7.)	3865	3990	4115	3930	4055	4180	3990	4115	4240	mV
V _{OL}	Output LOW Voltage (Note 7.)	3065	3190	3315	3130	3255	3380	3190	3315	3440	mV
V_{IH}	Input HIGH Voltage (Single Ended)	3790		4115	3855		4180	3915		4240	mV
V_{IL}	Input LOW Voltage (Single Ended)	3065		3390	3130		3455	3190		3515	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 8.)	2.0		5.0	2.0		5.0	2.0		5.0	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfpm is maintained.

- 6. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +2.0 V to -0.5 V.
- 7. All loading with 50 ohms to V_{CC} -2.0 volts.
- 8. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

10EP DC CHARACTERISTICS, NECL $V_{CC} = 0 \text{ V}$, $V_{EE} = -5.5 \text{ V}$ to -3.0 V (Note 9.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	26	34	44	26	35	45	28	37	47	mA
V _{OH}	Output HIGH Voltage (Note 10.)	-1135	-1010	-885	-1070	-945	-820	-1010	-885	-760	mV
V _{OL}	Output LOW Voltage (Note 10.)	-1935	-1810	-1685	-1870	-1745	-1620	-1810	-1685	-1560	mV
V_{IH}	Input HIGH Voltage (Single Ended)	-1210		-885	-1145		-820	-1085		-760	mV
V_{IL}	Input LOW Voltage (Single Ended)	-1935		-1610	-1870		-1545	-1810		-1485	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 11.)	V _{EE}	+2.0	0.0	V _{EE}	+2.0	0.0	V _{EE}	+2.0	0.0	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfpm is maintained.

- 9. Input and output parameters vary 1:1 with V_{CC}.
- 10. All loading with 50 ohms to V_{CC}-2.0 volts.
- 11. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

100EP DC CHARACTERISTICS, PECL $V_{CC} = 3.3 \text{ V}$, $V_{EE} = 0 \text{ V}$ (Note 12.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	26	34	44	26	35	45	28	37	47	mA
V _{OH}	Output HIGH Voltage (Note 13.)	2155	2280	2405	2155	2280	2405	2155	2280	2405	mV
V _{OL}	Output LOW Voltage (Note 13.)	1355	1480	1605	1355	1480	1605	1355	1480	1605	mV
V _{IH}	Input HIGH Voltage (Single Ended)	2075		2420	2075		2420	2075		2420	mV
V _{IL}	Input LOW Voltage (Single Ended)	1355		1675	1355		1675	1355		1675	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 14.)	2.0		3.3	2.0		3.3	2.0		3.3	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfpm is maintained.

100EP DC CHARACTERISTICS, PECL $V_{CC} = 5.0 \text{ V}$, $V_{EE} = 0 \text{ V}$ (Note 15.)

			-40°C	_		25°C	_		85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	26	34	44	26	35	45	28	37	47	mA
V _{OH}	Output HIGH Voltage (Note 16.)	3855	3980	4105	3855	3980	4105	3855	3980	4105	mV
V _{OL}	Output LOW Voltage (Note 16.)	3055	3180	3305	3055	3180	3305	3055	3180	3305	mV
V_{IH}	Input HIGH Voltage (Single Ended)	3775		4120	3775		4120	3775		4120	mV
V_{IL}	Input LOW Voltage (Single Ended)	3055		3375	3055		3375	3055		3375	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 17.)	2.0		5.0	2.0		5.0	2.0		5.0	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfpm is maintained.

100EP DC CHARACTERISTICS, NECL $V_{CC} = 0 \text{ V}$, $V_{EE} = -5.5 \text{ V}$ to -3.0 V (Note 18.)

			–40°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	
I _{EE}	Power Supply Current	26	34	44	26	35	45	28	37	47	mA	
V _{OH}	Output HIGH Voltage (Note 19.)	-1145	-1020	-895	-1145	-1020	-895	-1145	-1020	-895	mV	
V _{OL}	Output LOW Voltage (Note 19.)	-1945	-1820	-1695	-1945	-1820	-1695	-1945	-1820	-1695	mV	
V _{IH}	Input HIGH Voltage (Single Ended)	-1225		-880	-1225		-880	-1225		-880	mV	
V_{IL}	Input LOW Voltage (Single Ended)	-1945		-1625	-1945		-1625	-1945		-1625	mV	
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 20.)	V _{EE}	+2.0	0.0	V _{EE}	+2.0	0.0	V _{EE}	+2.0	0.0	V	
I _{IH}	Input HIGH Current			150			150			150	μΑ	
I _{IL}	Input LOW Current	0.5			0.5			0.5			μΑ	

NOTE: EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfpm is maintained.

^{12.} Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.3 V to -2.2 V.

^{13.} All loading with 50 ohms to V_{CC} –2.0 volts.

^{14.} V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

^{15.} Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +2.0 V to -0.5 V.

^{16.} All loading with 50 ohms to V_{CC} –2.0 volts.

^{17.} V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

^{18.} Input and output parameters vary 1:1 with V_{CC} .

^{19.} All loading with 50 ohms to V_{CC}-2.0 volts.

^{20.} V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

 $\textbf{AC CHARACTERISTICS} \ \, \text{V}_{\text{CC}} = 0 \ \, \text{V}; \ \, \text{V}_{\text{EE}} = -3.0 \ \, \text{V to} \, \, -5.5 \ \, \text{V} \quad \text{or} \quad \, \text{V}_{\text{CC}} = 3.0 \ \, \text{V to} \, \, 5.5 \ \, \text{V}; \ \, \text{V}_{\text{EE}} = 0 \ \, \text{V} \, \, \text{(Note 21.)}$

	00 , EE		U	•				•			
			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Frequency (See Figure 2. F _{max} /JITTER)		> 3			> 3			> 3		GHz
t _{PLH} , t _{PHL}	Propagation Delay to Output Differential CLK, $\overline{\text{CLK}}$ to Q, $\overline{\text{Q}}$ 10 100 RESET to Q, $\overline{\text{Q}}$	250 275 300	300 340 380	350 425 450	270 300 325	320 375 400	370 450 475	300 350 350	350 425 425	420 500 500	ps
t _{RR}	Reset Recovery	150			150			150			ps
t _S	Setup Time Hold Time	100 100			100 100	80 40		100 100			ps
t _{PW}	Minimum Pulse Width RESET	500	440		500	440		500	440		ps
t _{JITTER}	Cycle-to-Cycle Jitter (See Figure 2. F _{max} /JITTER)		.2	< 1		.2	< 1		.2	< 1	ps
t _r t _f	Output Rise/Fall Times Q, $\overline{\mathbb{Q}}$ (20% – 80%)	70	120	170	80	130	180	100	150	200	ps

^{21.} Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50 ohms to V_{CC}-2.0 V.

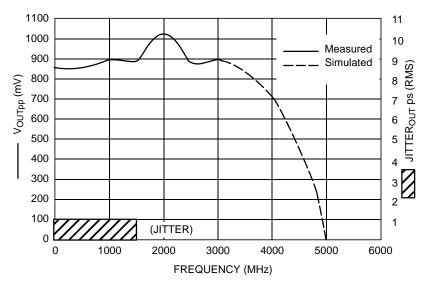


Figure 2. F_{max}/Jitter

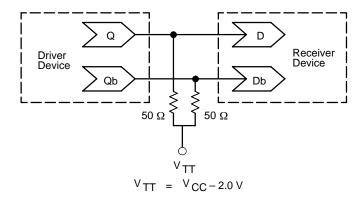


Figure 3. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020 – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1404 – ECLinPS Circuit Performance at Non–Standard V_{IH} Levels

AN1405 – ECL Clock Distribution Techniques

AN1406 – Designing with PECL (ECL at +5.0 V)

AN504 – Metastability and the ECLinPS Family

AN1568 – Interfacing Between LVDS and ECL

AN1650 – Using Wire–OR Ties in ECLinPS Designs

AN1672 – The ECL Translator Guide

AND8001 – Odd Number Counters Design

AND8002 – Marking and Date Codes

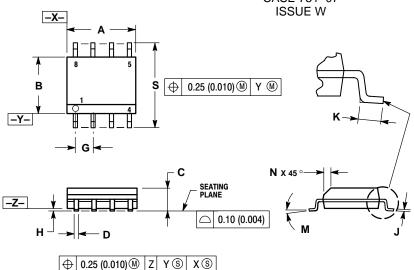
AND8009 – ECLinPS Plus Spice I/O Model Kit

AND8020 – Termination of ECL Logic Devices

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PACKAGE DIMENSIONS

SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-07



NOTES:

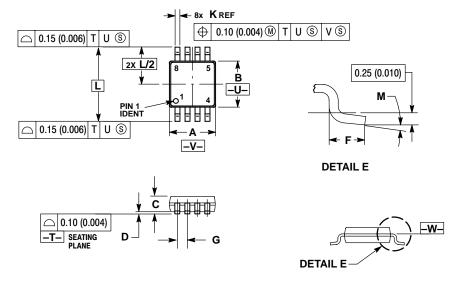
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 Y14.5M. 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.

 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER
- SIDE.

 DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN
 EXCESS OF THE D DIMENSION AT MAXIMUM
 MATERIAL CONDITION.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27 BSC		0.050 BSC		
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
M	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

TSSOP-8 **DT SUFFIX** PLASTIC TSSOP PACKAGE CASE 948R-02 ISSUE A



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH.
 PROTRUSIONS OR GATE BURRS. MOLD FLASH
 OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION B DOES NOT INCLUDE INTERLEAD
- FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.

 6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
С	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65 BSC		0.026 BSC	
K	0.25	0.40	0.010	0.016
L	4.90 BSC		0.193 BSC	
M	0°	6 °	0°	6°

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